NSN 5961-00-004-5556

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-004-5556 **Inclosure Material:** Glass **Overall Length:** 0.250 inches **Overall Diameter:** Between 0.170 inches and 0.250 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 collector to base voltage, dc **Current Rating Per Characteristic:** 1.00 amperes collector current, dc **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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